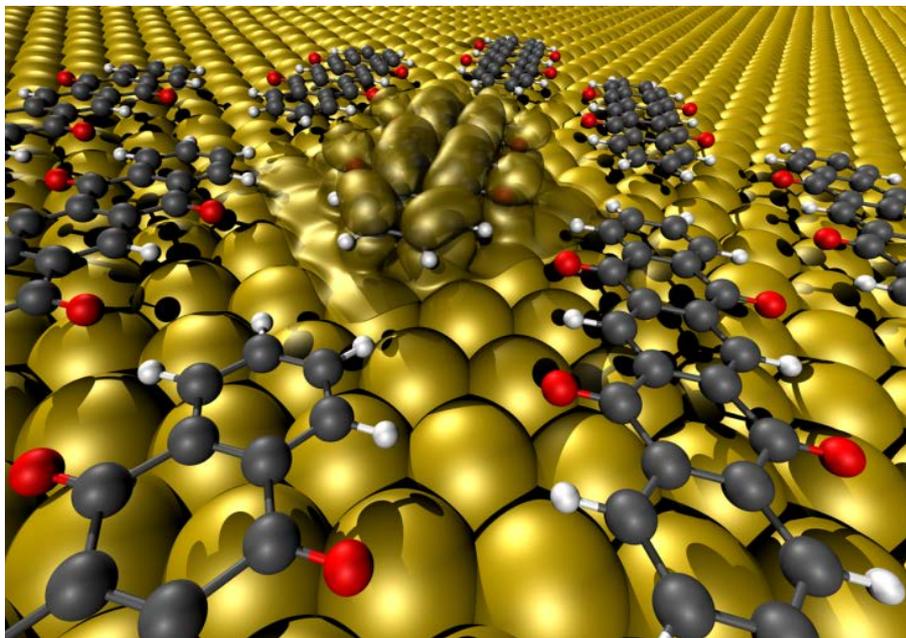


Vertical Adsorption Distances Impact Energetics at Organic-Metal Interfaces



FUNSOM

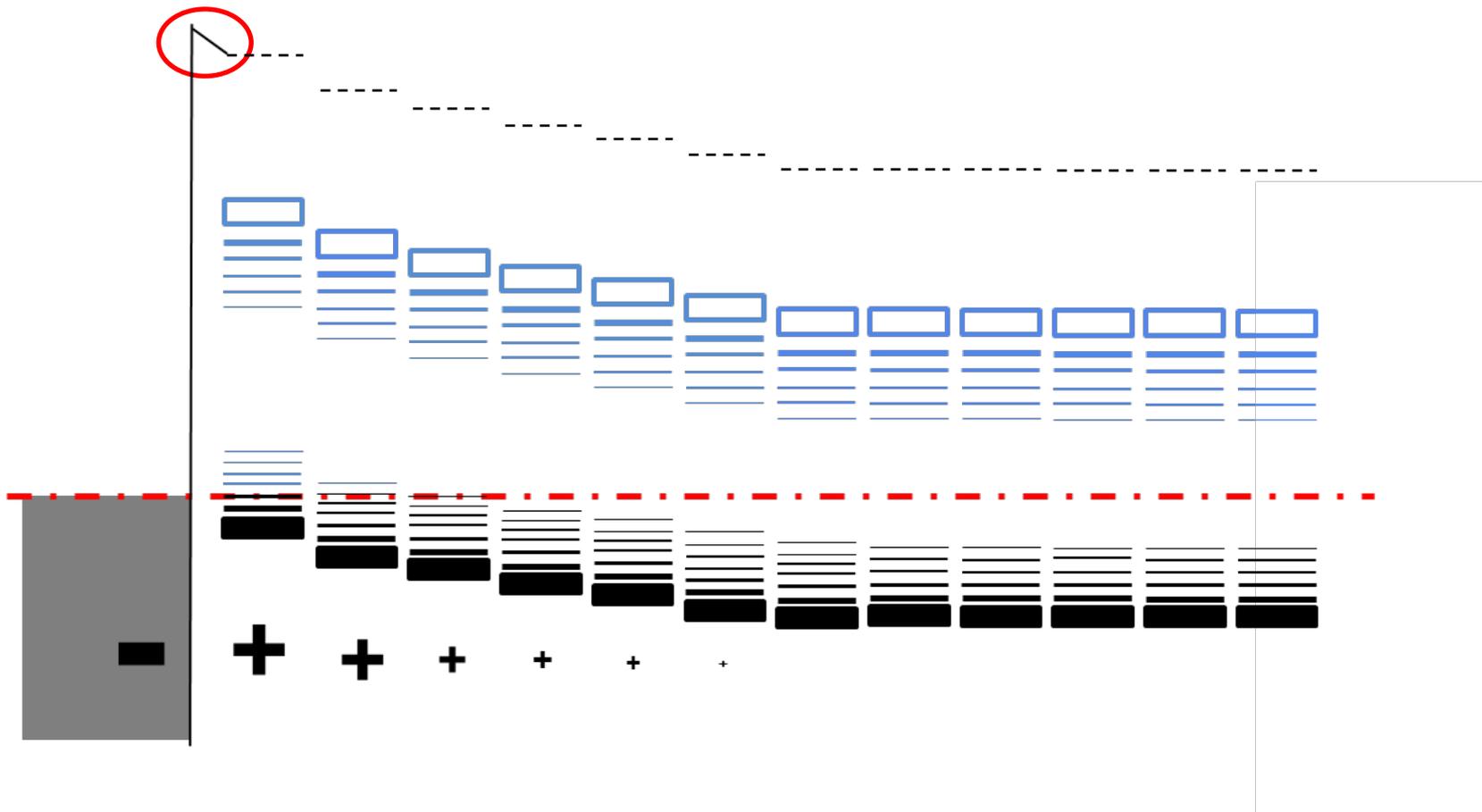
功能纳米与软物质研究院
Institute of Functional Nano & Soft Materials

Steffen Duhm



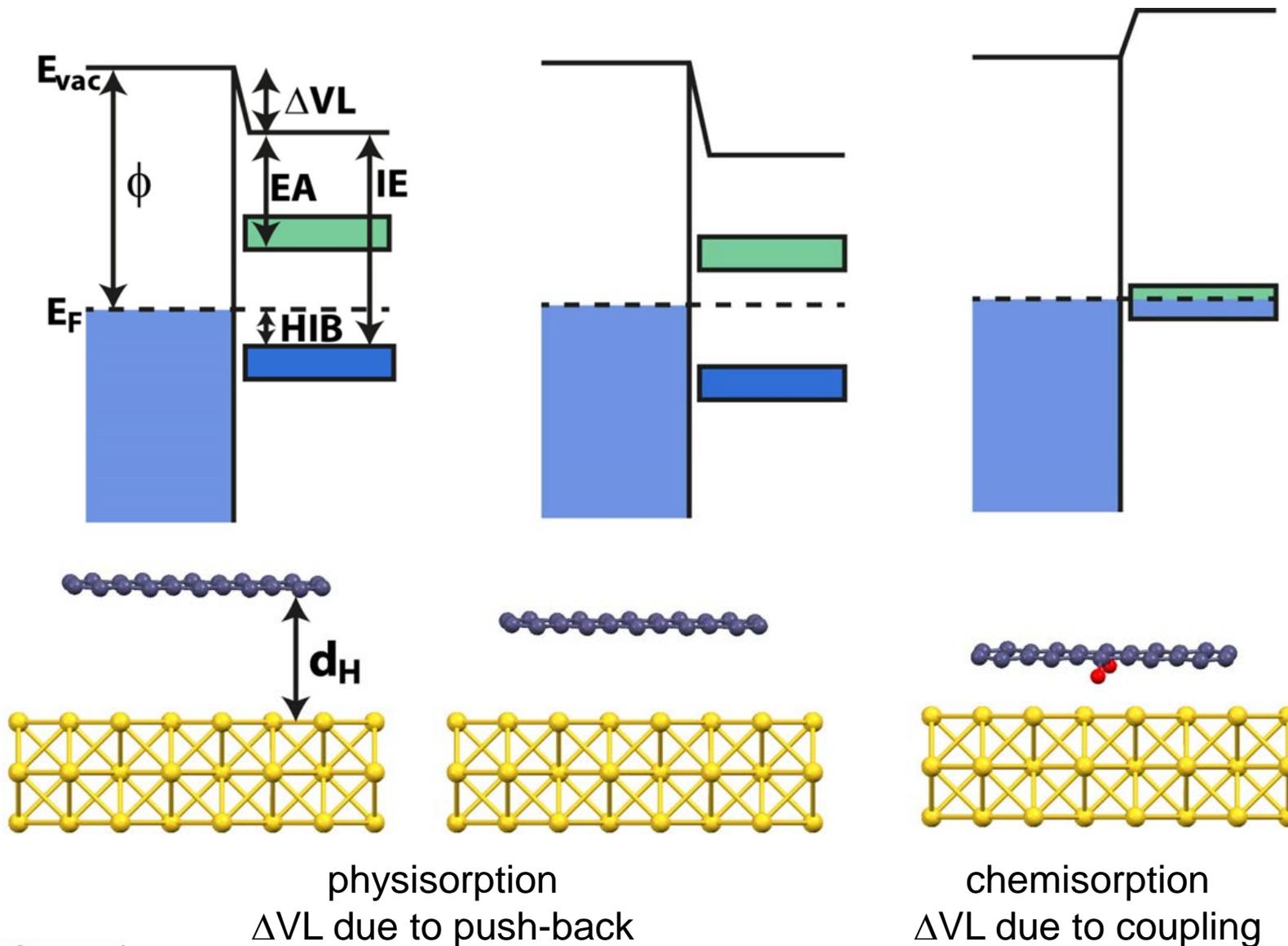
蘇州大學

Soochow
University

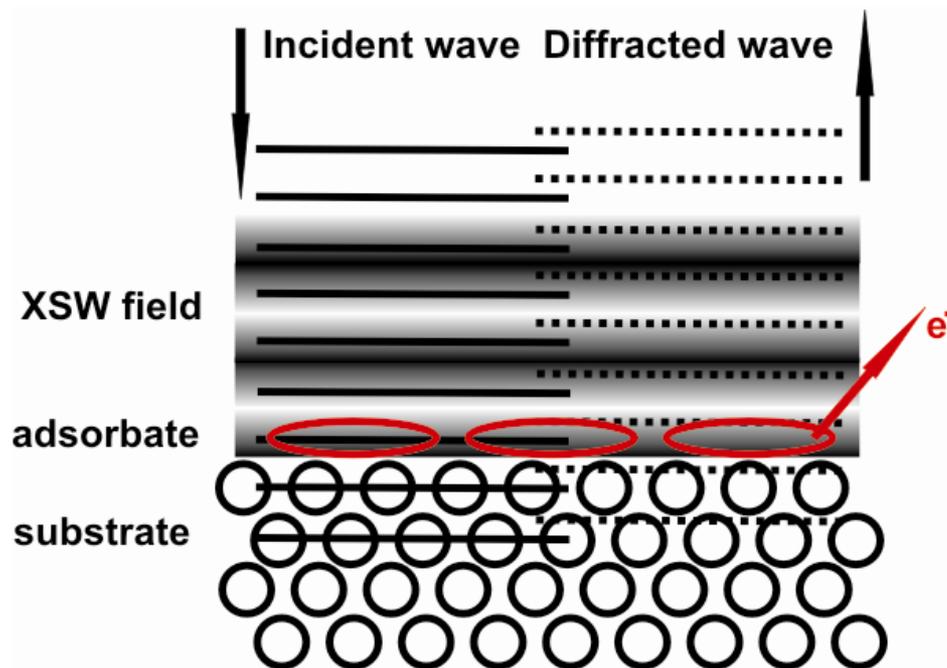


The energy-level alignment at organic-inorganic interfaces is controlled by the density of states of frontier molecular orbitals.

Organic-metal interface energetics







With the XSW technique element-specific bonding distances of organic (sub)monolayers on metal single crystals can be determined with high precision.

The photoelectron yield (intensity of XPS signal) of the adsorbate is measured in the standing wave field of incident and diffracted X-ray wave.

$$I(\theta, \mathbf{r}) = \frac{|\mathbf{E}_0 + \mathbf{E}_H|^2}{|E_0|^2}$$

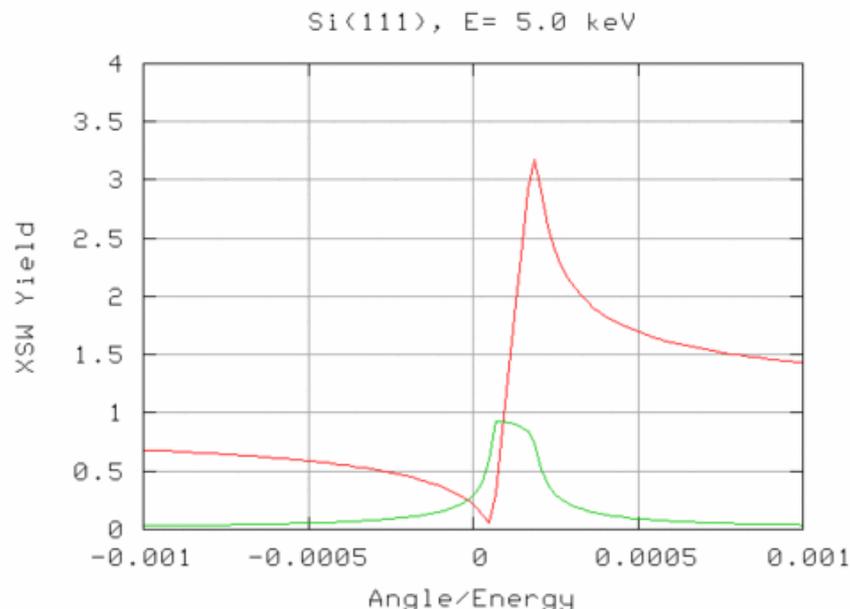
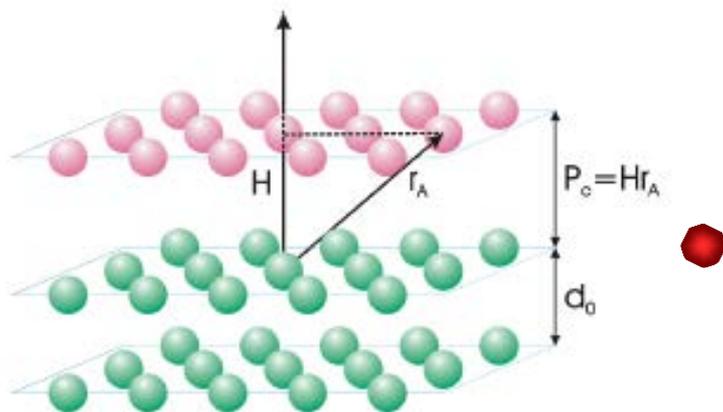
$$= \left(1 + R(\theta) + 2\sqrt{R(\theta)} \cos(\nu(\theta) - \mathbf{H} \cdot \mathbf{r}) \right) \times \begin{cases} 1 & : \text{above the surface} \\ \exp(-\mu_z(\theta)z) & : \text{below the surface} \end{cases}$$

Photoelectron yield from adsorbate (dipole approximation):

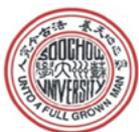
$$Y_p(\mathbf{r}) = 1 + R + 2C\sqrt{R}f_H \cos(\nu - 2\pi P_H)$$

- coherent position: P_H
- coherent fraction: $0 < f_H < 1$

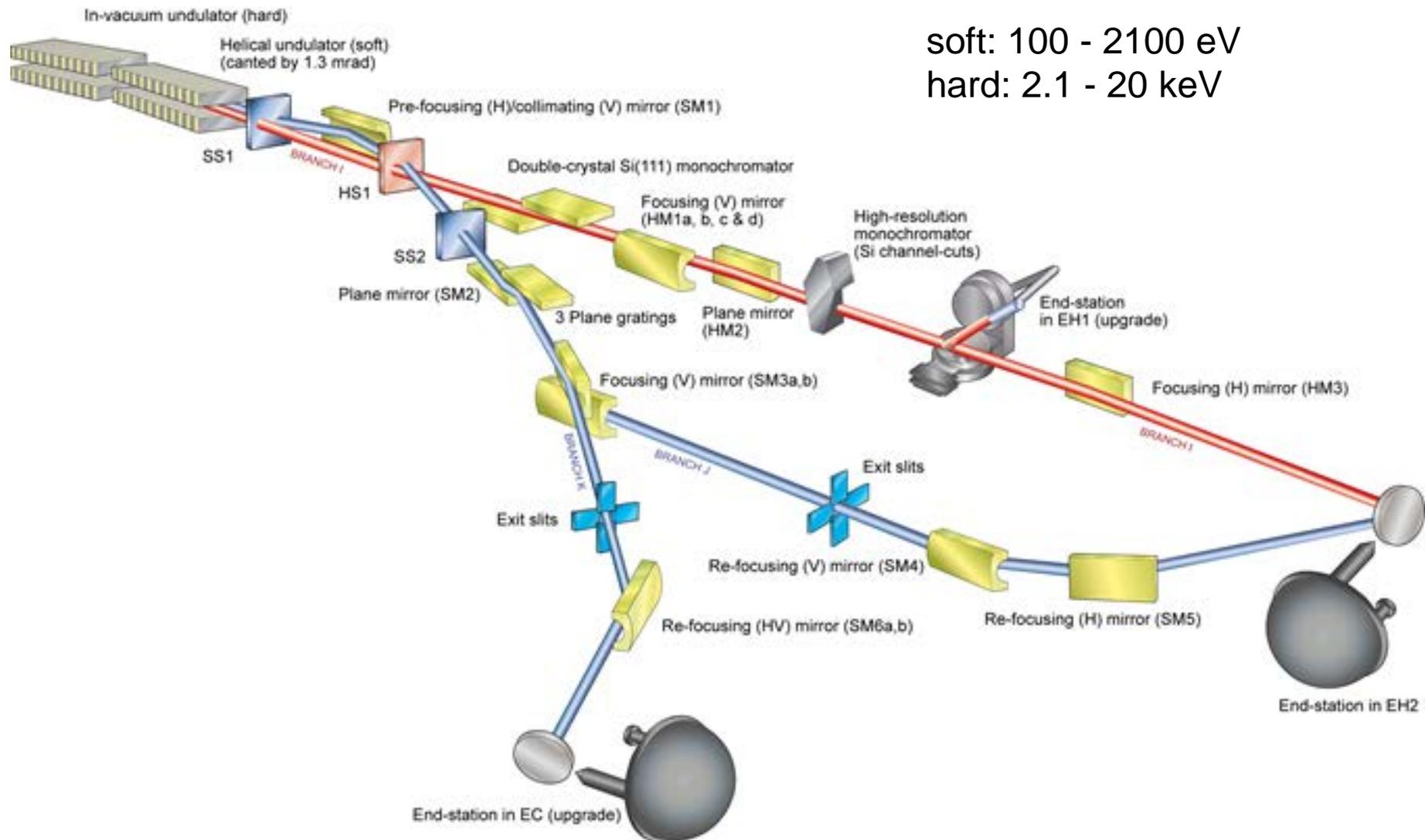
$$d_H = d_0(n + P_H) \text{ with } n = 0, 1, 2, \dots$$



Bragg-energy in normal incidence for Au(111), Ag(111), Cu(111)...: ~3 keV



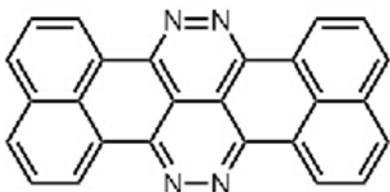
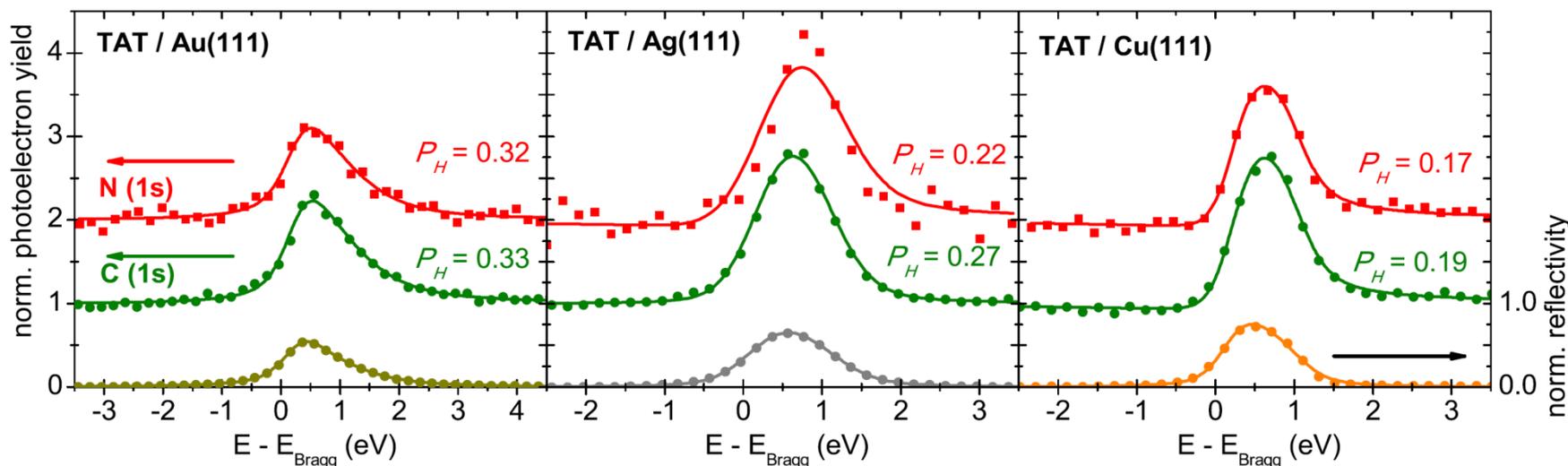
Beamline I09 @ Diamond



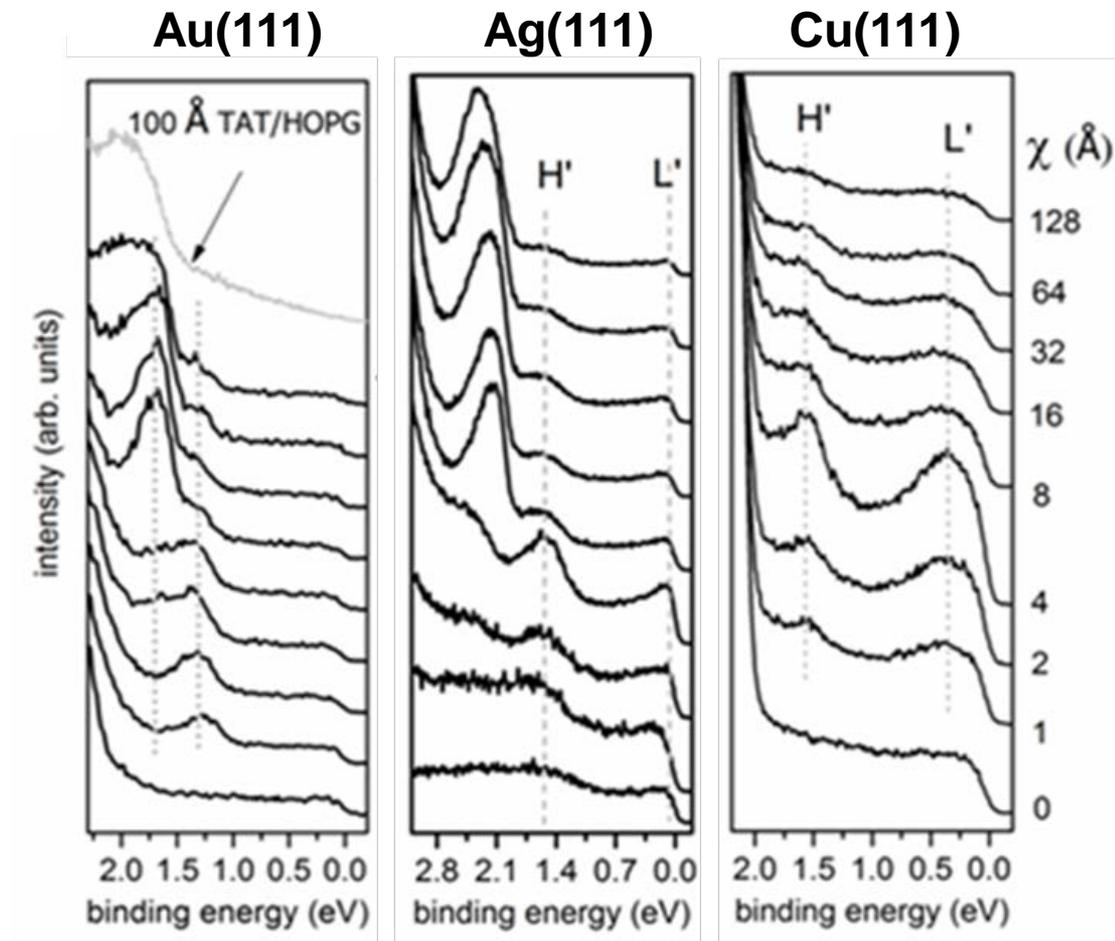
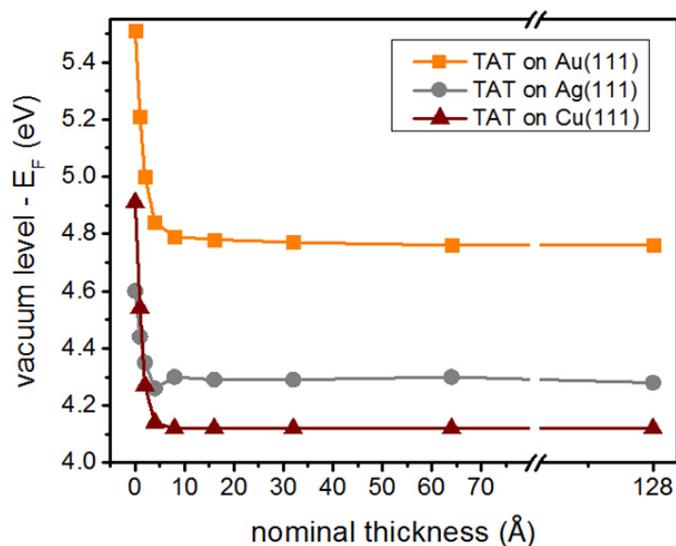
soft: 100 - 2100 eV

hard: 2.1 - 20 keV

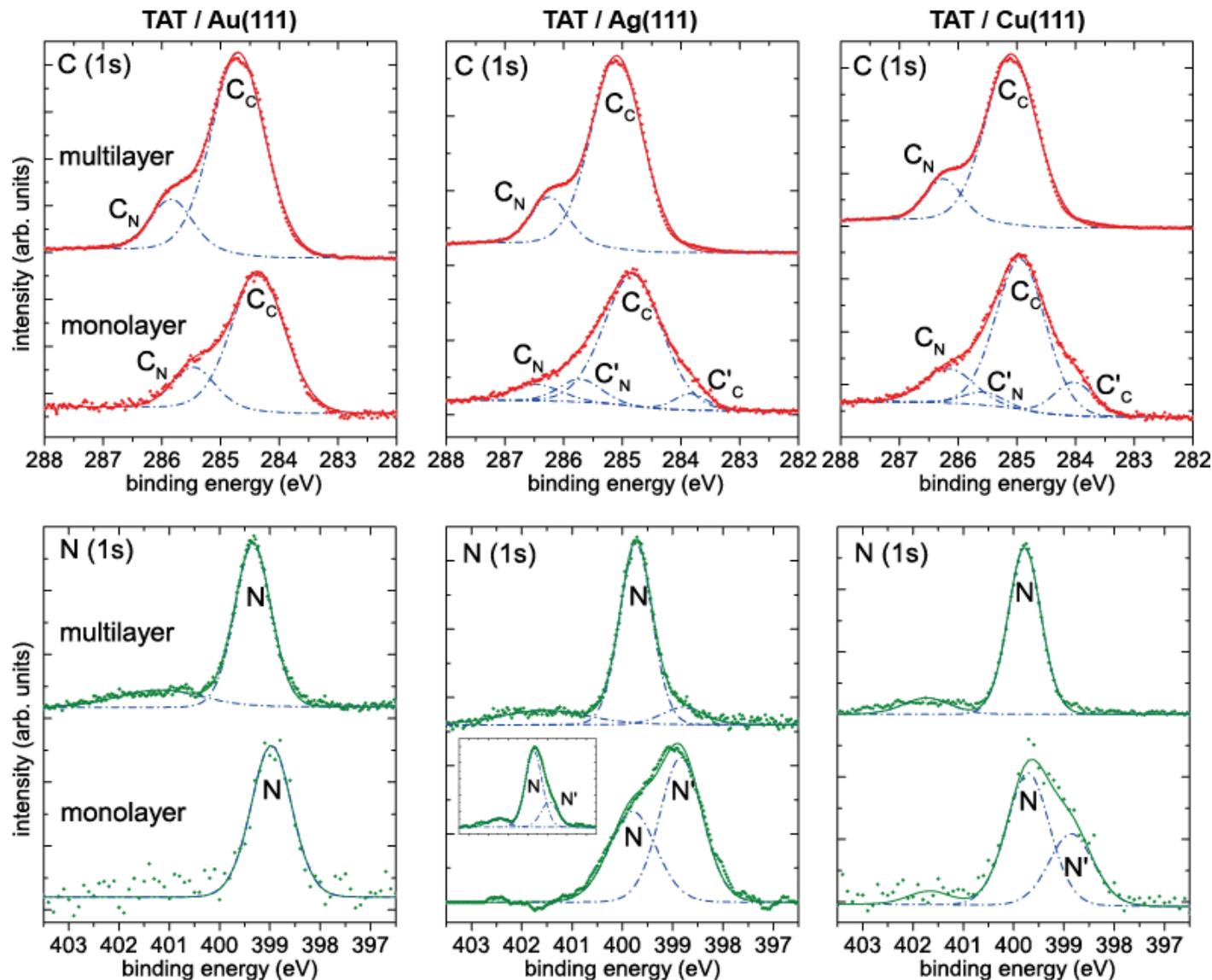
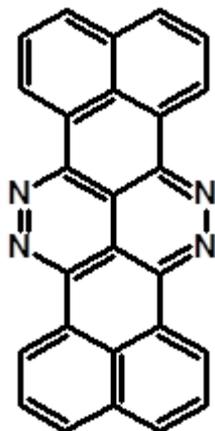
Bonding distances of tetraazaterrylene



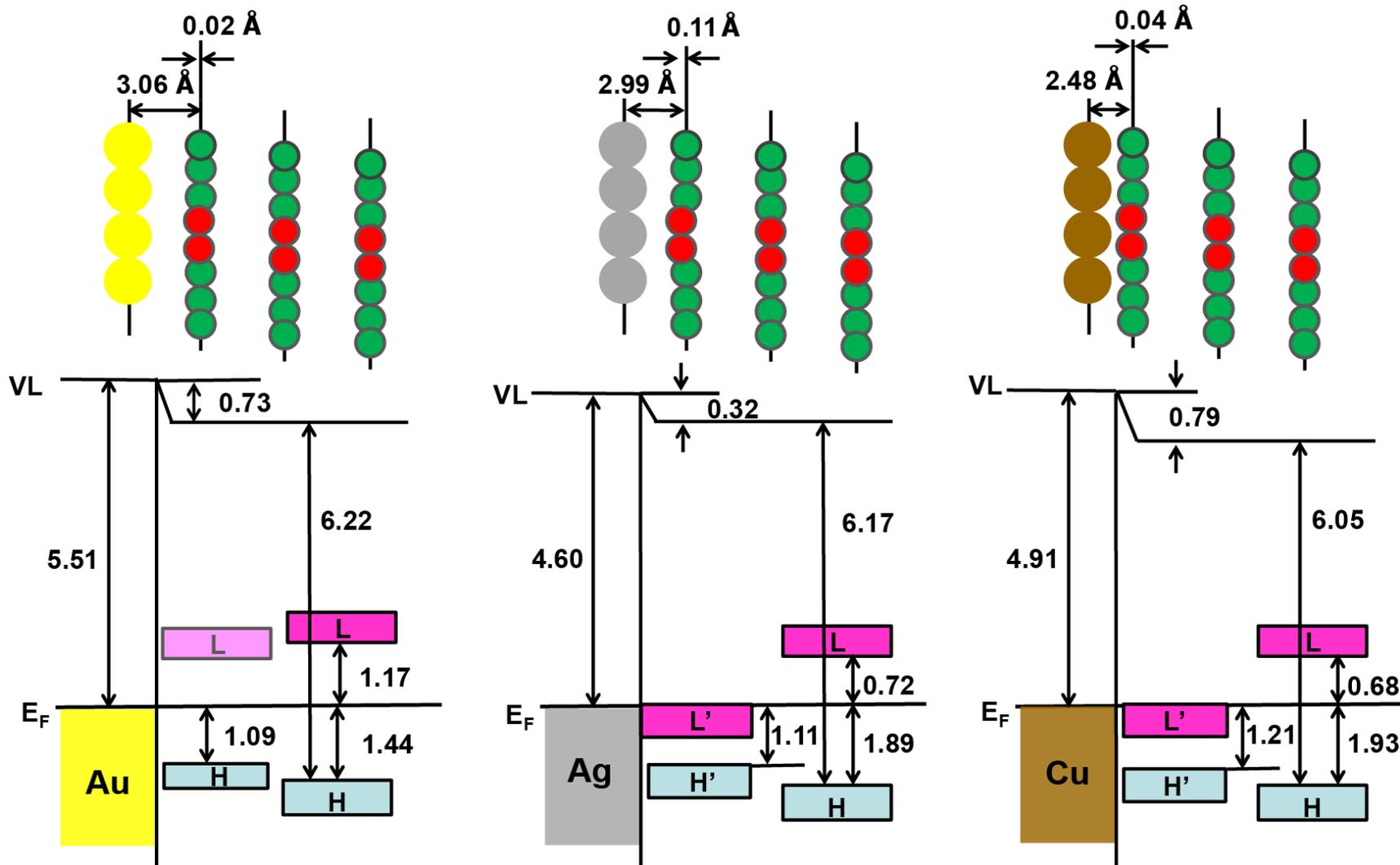
Substrate	Carbon			Nitrogen		
	f_H	P_H	$d_H(\text{Å})$	f_H	P_H	$d_H(\text{Å})$
Au(111)	0.39	0.33	3.06 ± 0.07	0.30	0.32	3.04 ± 0.02
Ag(111)	0.65	0.27	2.99 ± 0.05	0.92 ^a	0.22	2.88 ± 0.10
Cu(111)	0.53	0.19	2.48 ± 0.04	0.46	0.17	2.44 ± 0.06

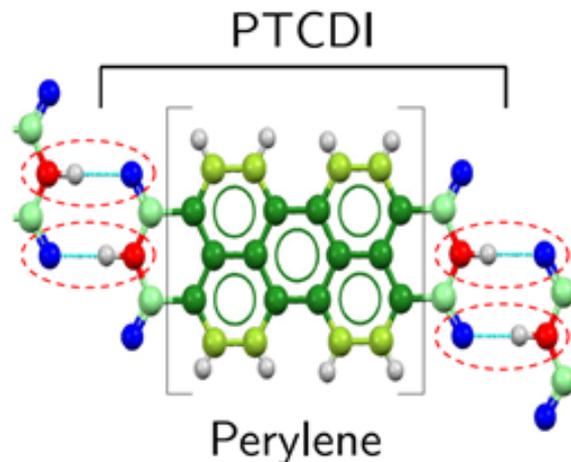


Tetraazaterrylene: XPS

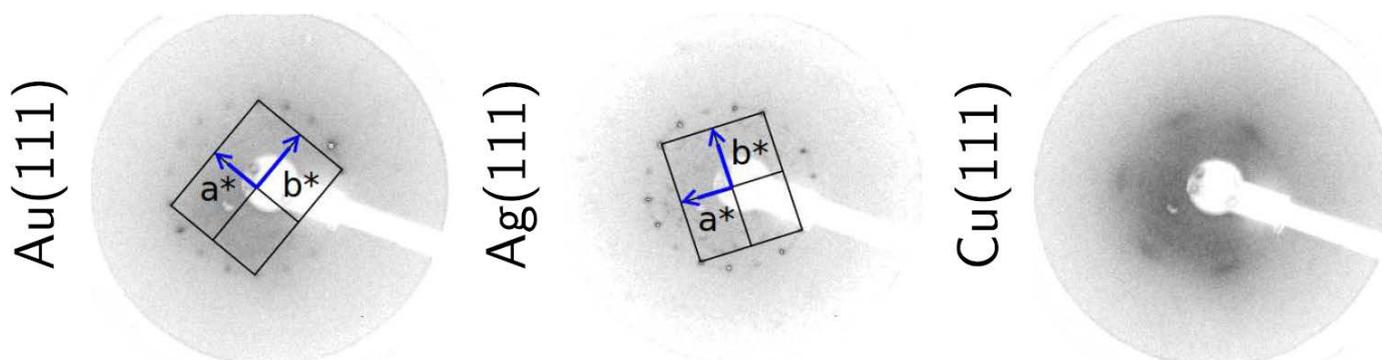


Tetraazaterrylene: ELA

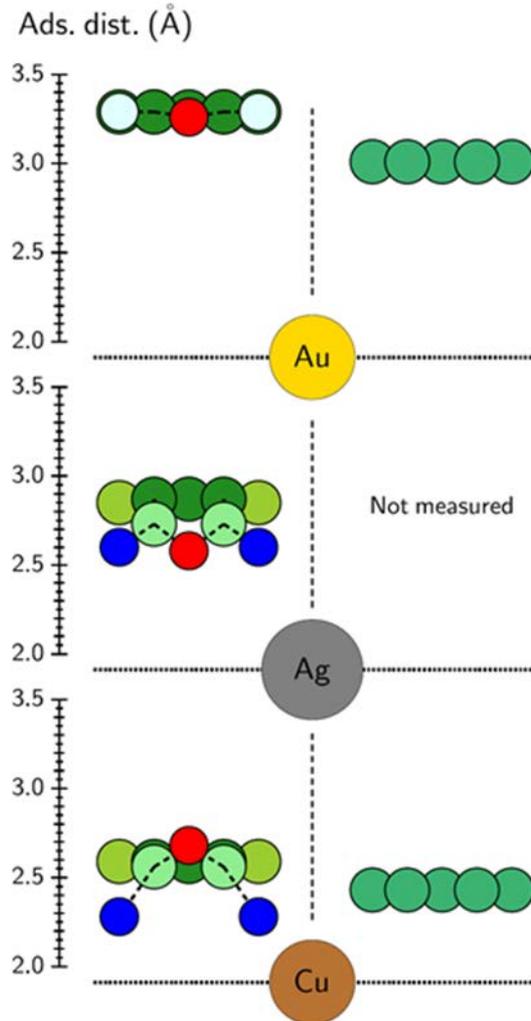
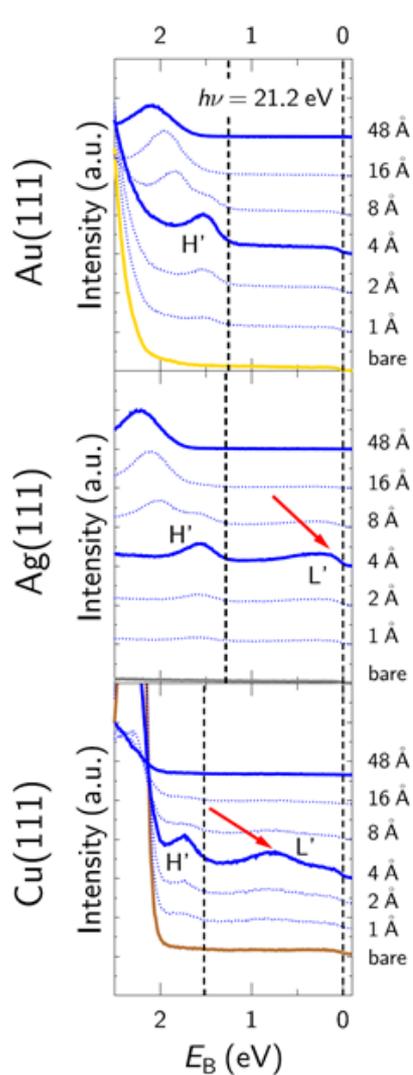




Perylene-3,4,9,10-tetracarboxylic diimide tends to N–H...O hydrogen-bond formation.



Almost no lateral order in PTCDI monolayers on Cu(111).

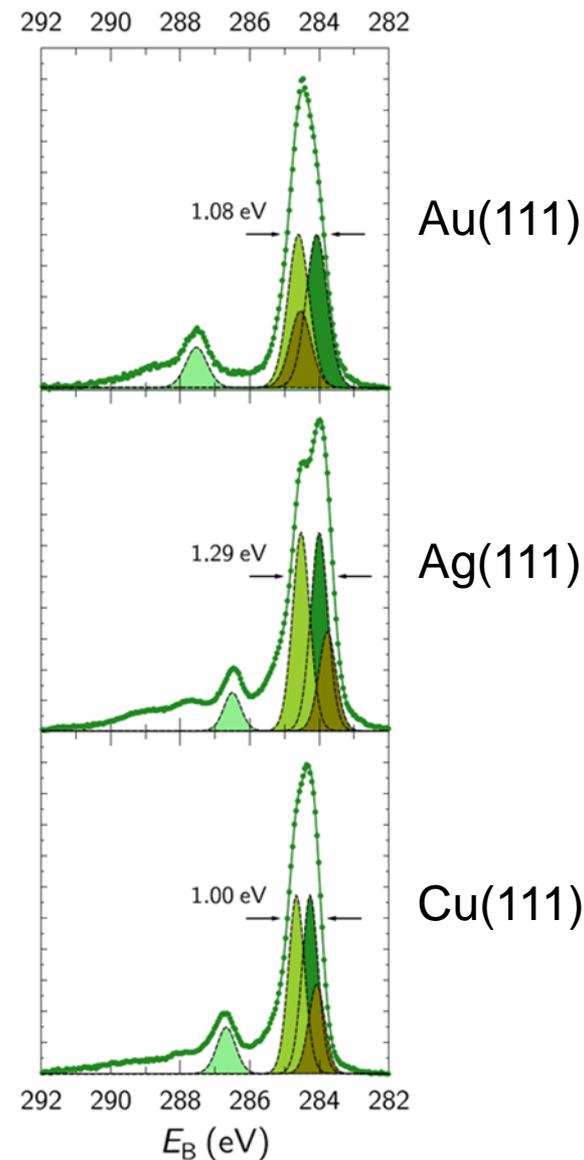
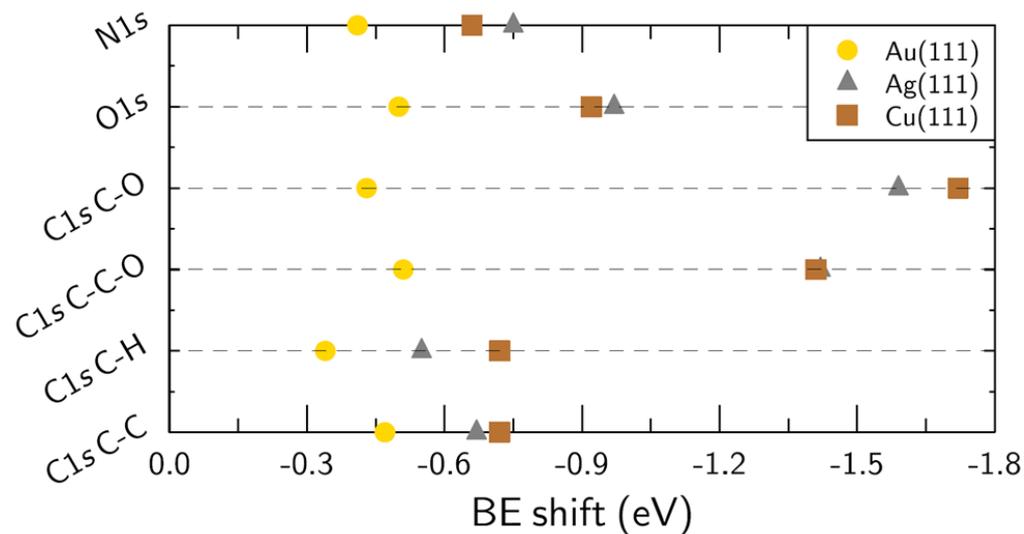
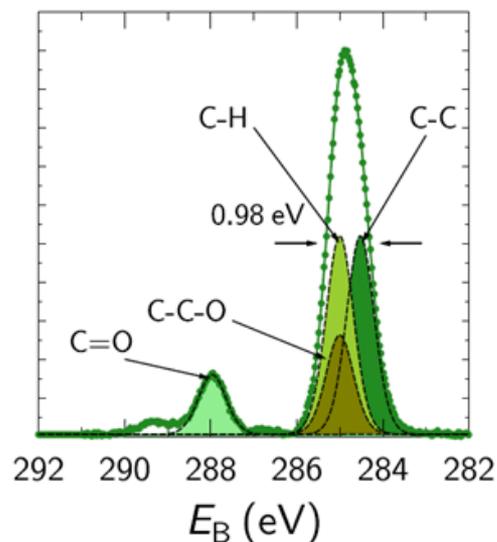


- physisorption
- large bonding distance
- chemisorption
- O (blue) and N (red) atoms: same bonding distance
- chemisorption
- O and N atoms: different bonding distances

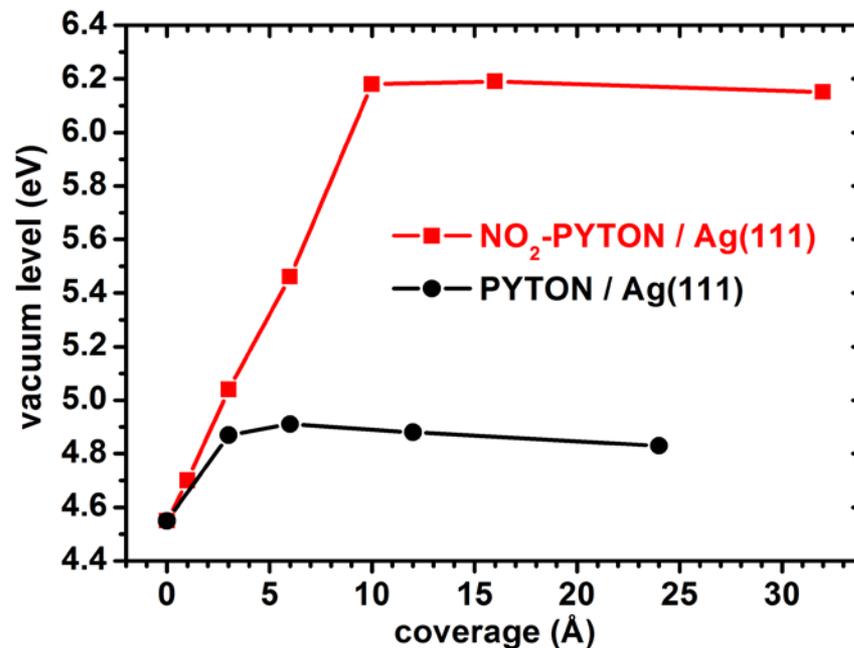
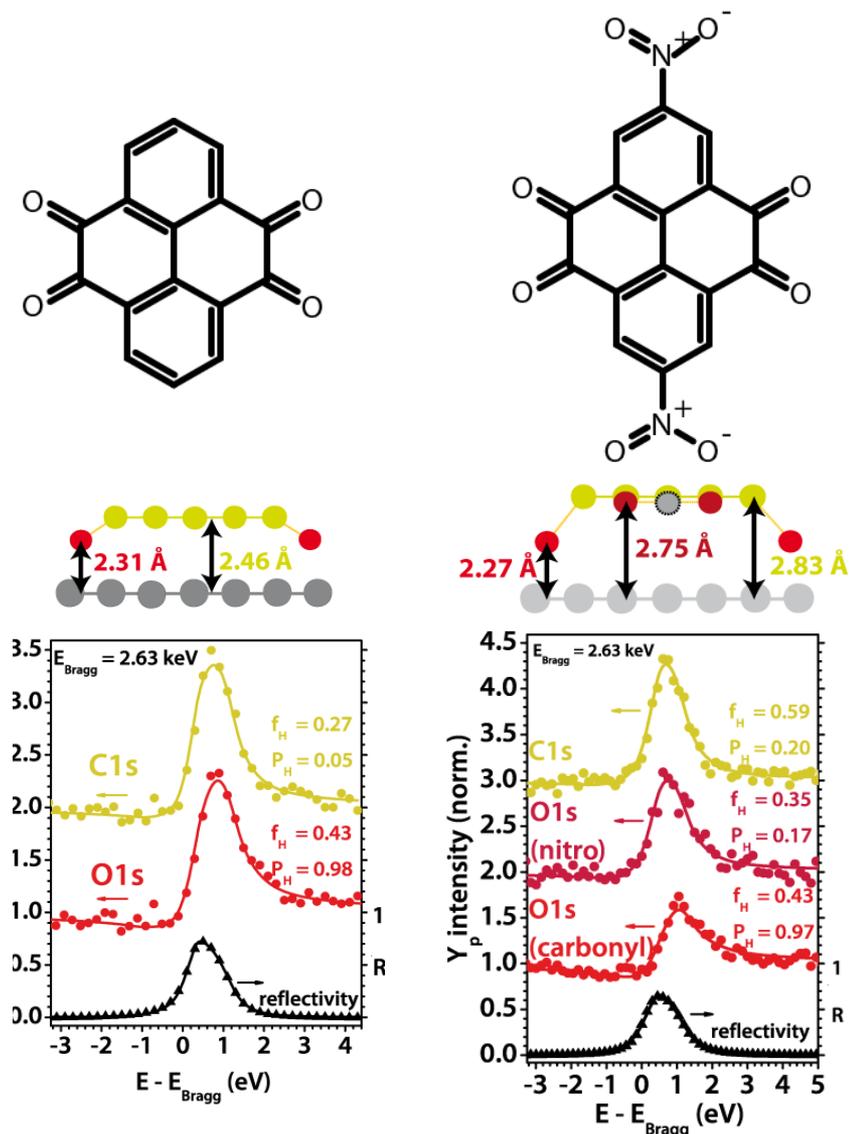
(Adsorption geometry of perylene for comparison.)



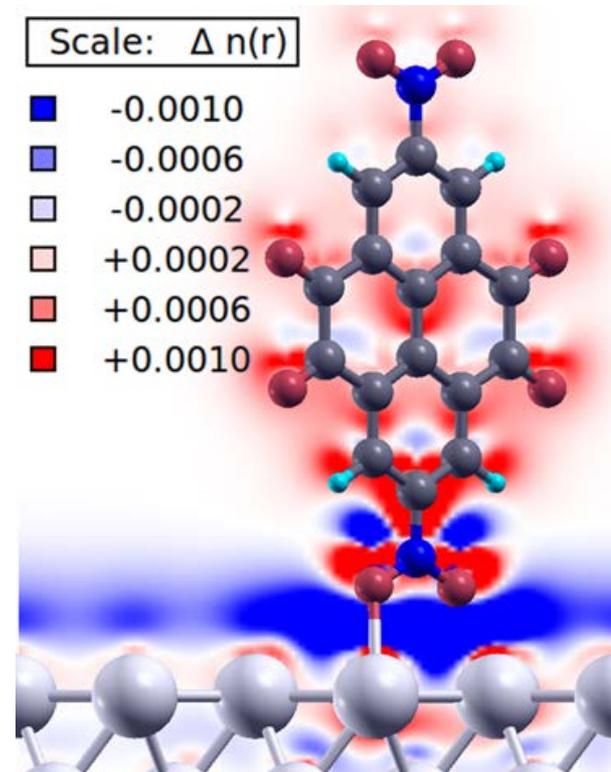
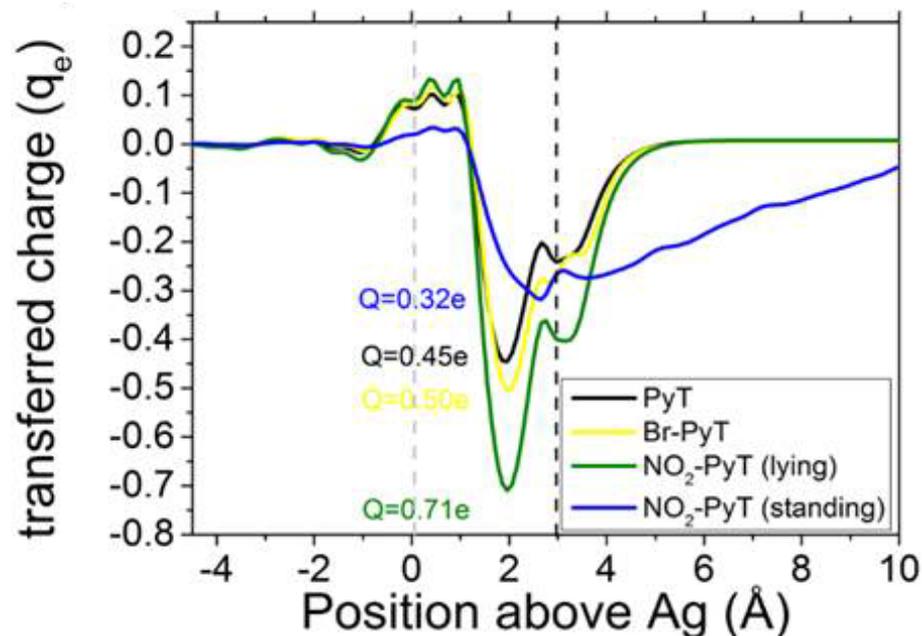
Fingerprints of bonding in core-level spectra



Monstrous work function increase



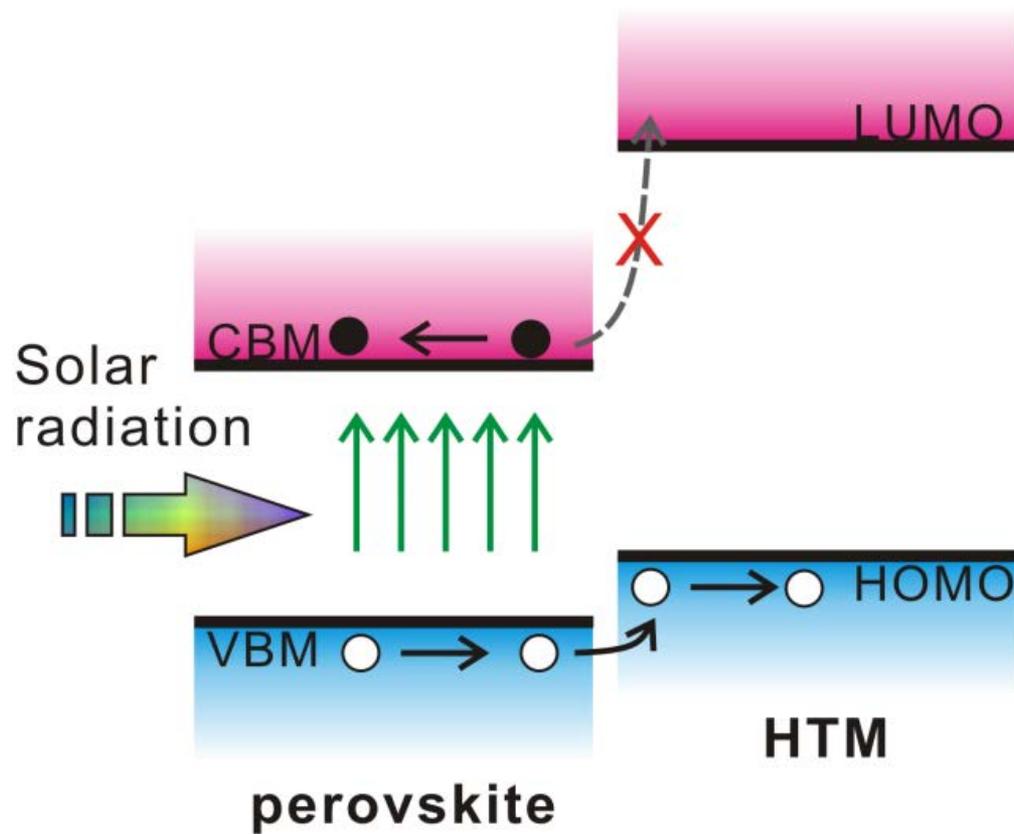
(NO_2 -)pyrene-tetraone / Ag(111)



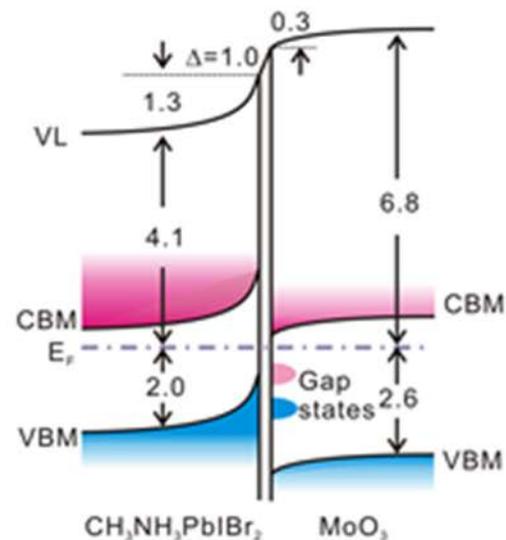
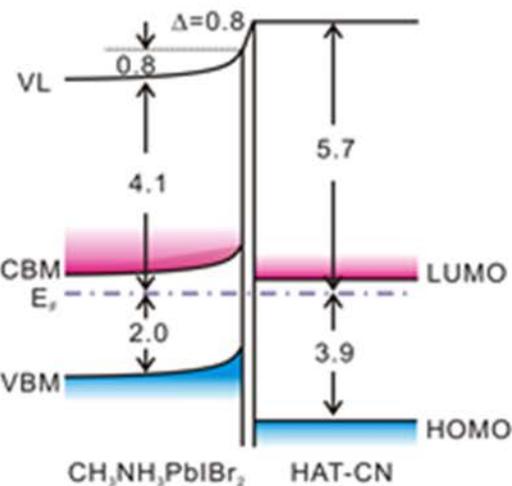
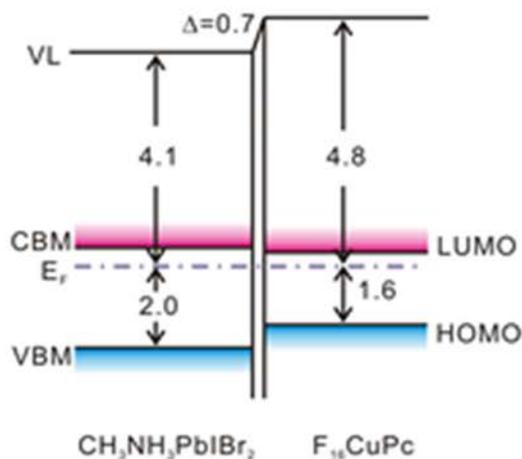
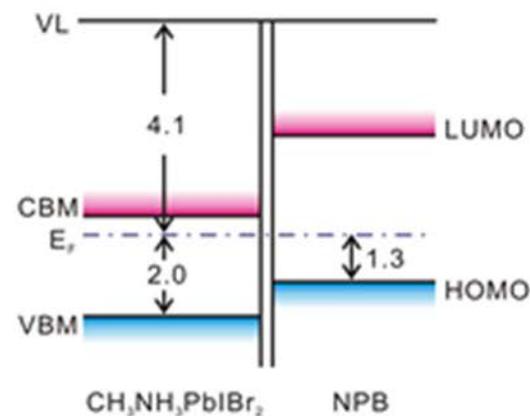
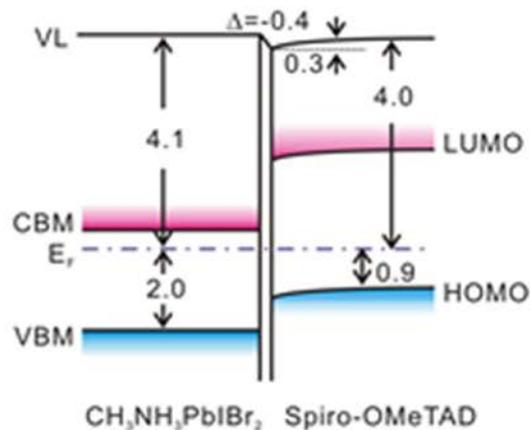
A reorientation from lying to standing NO_2 -PYTON in monolayers on Ag(111) decreases the average charge transfer per molecule but increases the work function.

How are these academic interfaces related to
Nano and Giga Challenges?

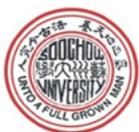
Perovskite solar cell: Energy-level alignment



CH₃NH₃PbI₂: ELA with OSCs



CH₃NH₃PbI₂ spin-coated on ZnO-coated ITO

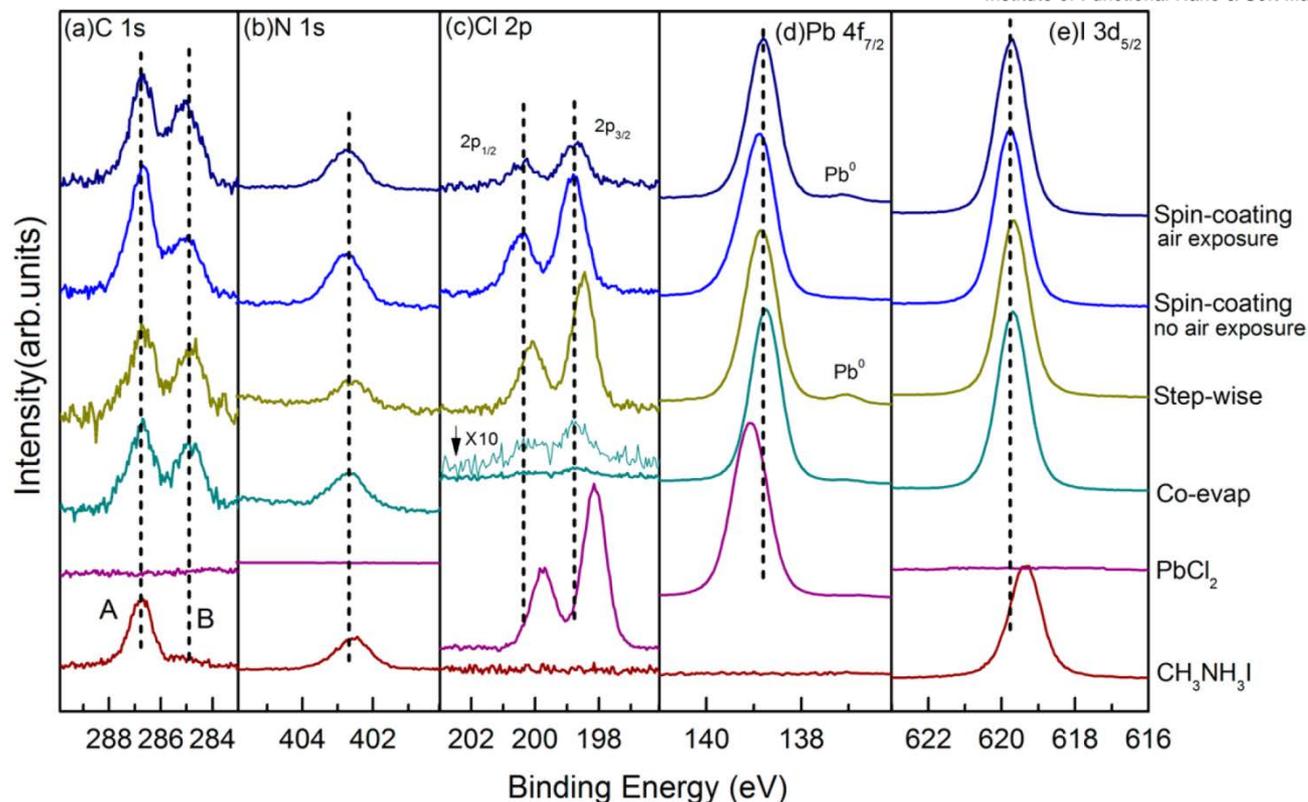


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Soochow University

Wang, Wang, Shen, Li, Li, Liu, Duhm, Tang, *Adv. Mater. Interfaces* **2**, 1400528 (2015)

A: CH_3NH_3
B: CH_3I



C1s, N1s

- same positions
- different relative intensity
- cation rearrangement

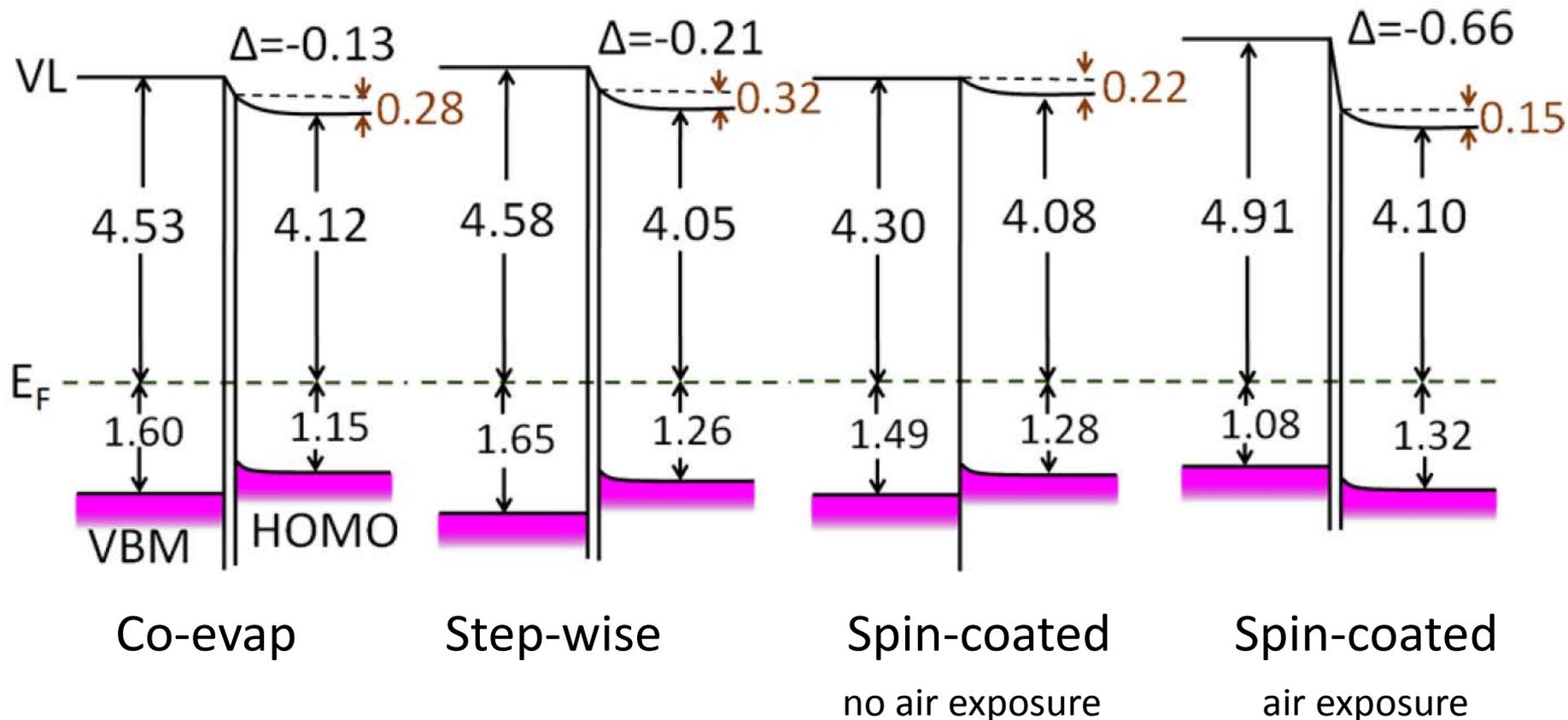
Cl2p, Pb4f, I3d

- different positions
- interaction between PbCl_2 and $\text{CH}_3\text{NH}_3\text{I}$
- step-wise: mixture of perovskite and unreacted PbCl_2



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Co-evap

Step-wise

Spin-coated

no air exposure

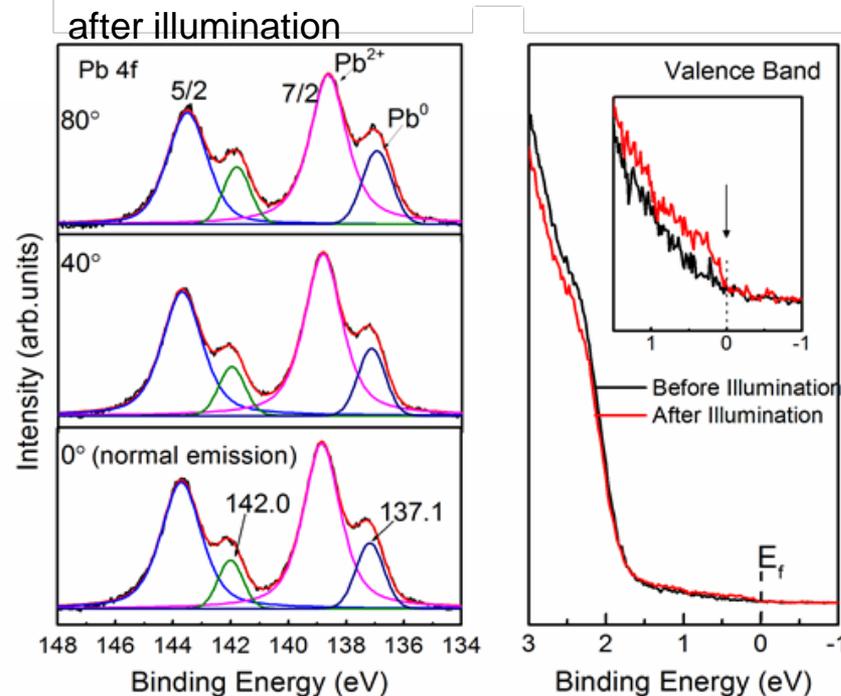
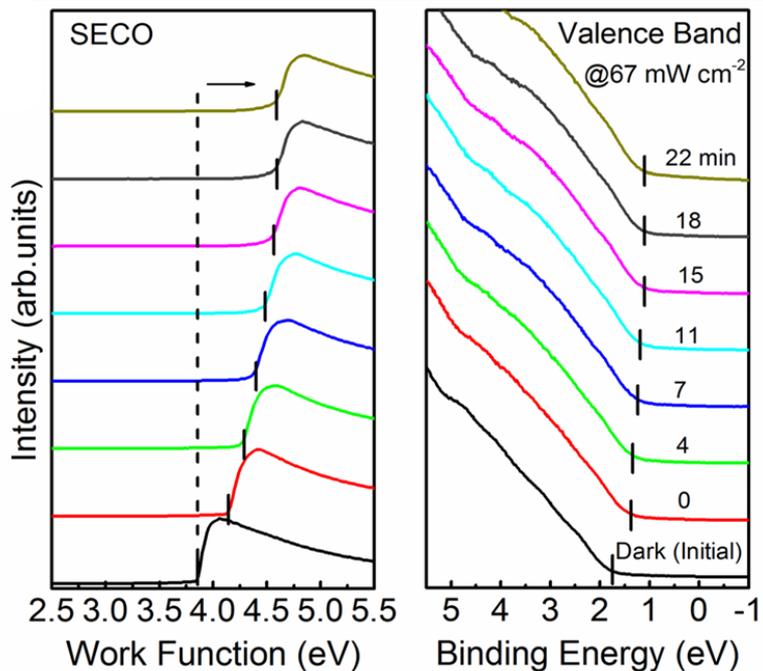
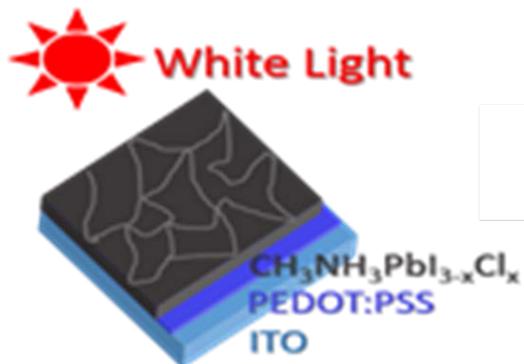
Spin-coated

air exposure

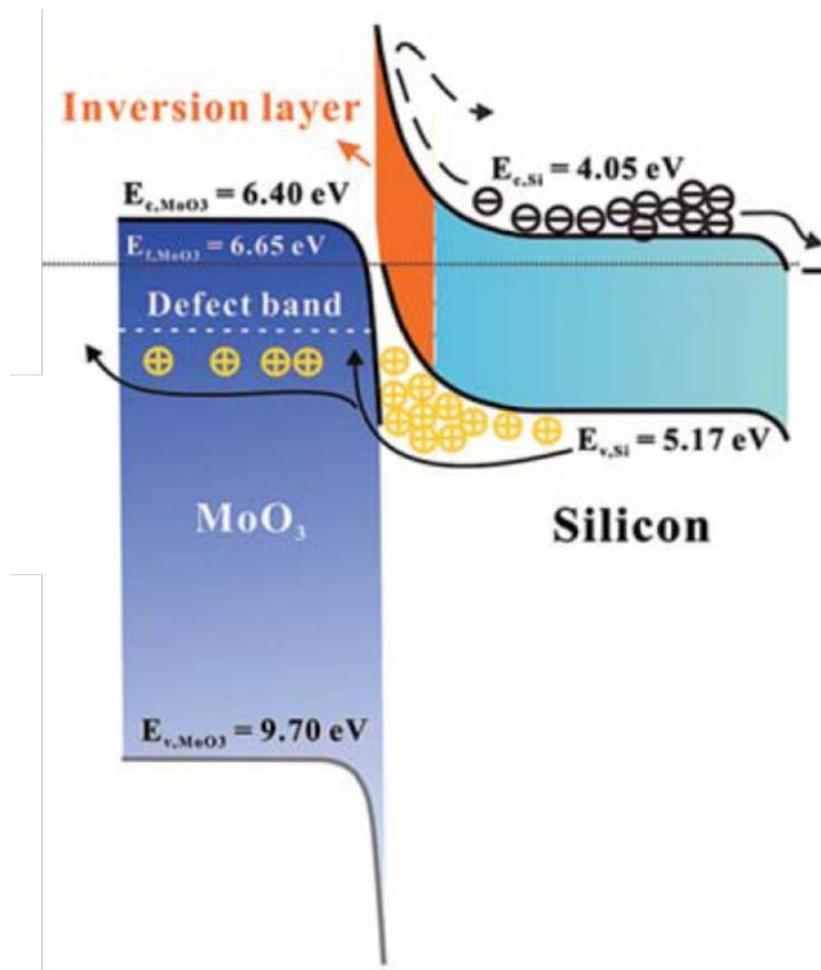
- no band bending on perovskite site.
- almost same band bending on NPB side.
- large interface dipole by air exposure by cation rearrangement.



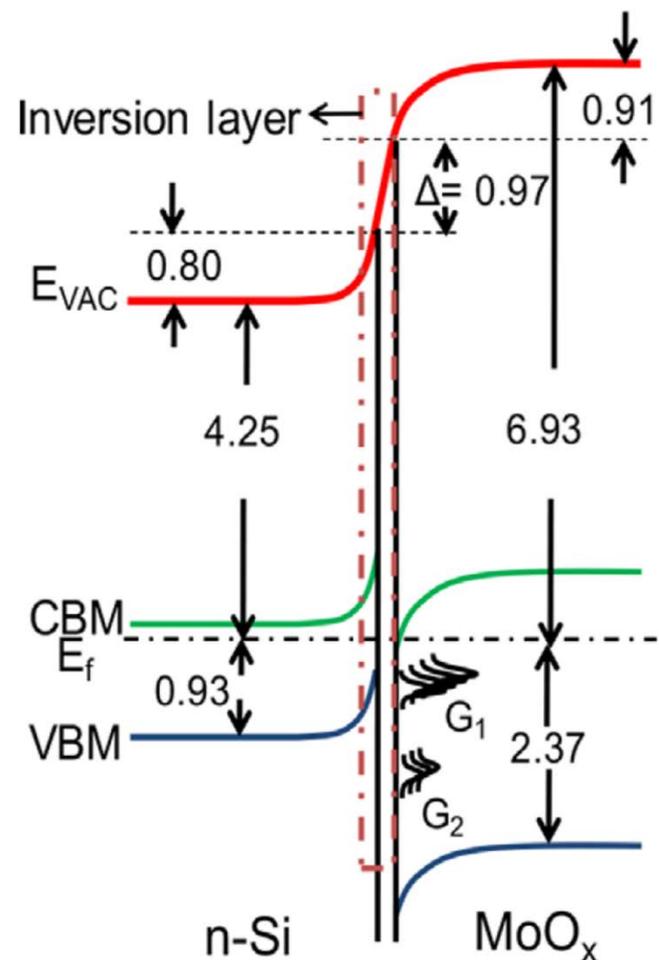
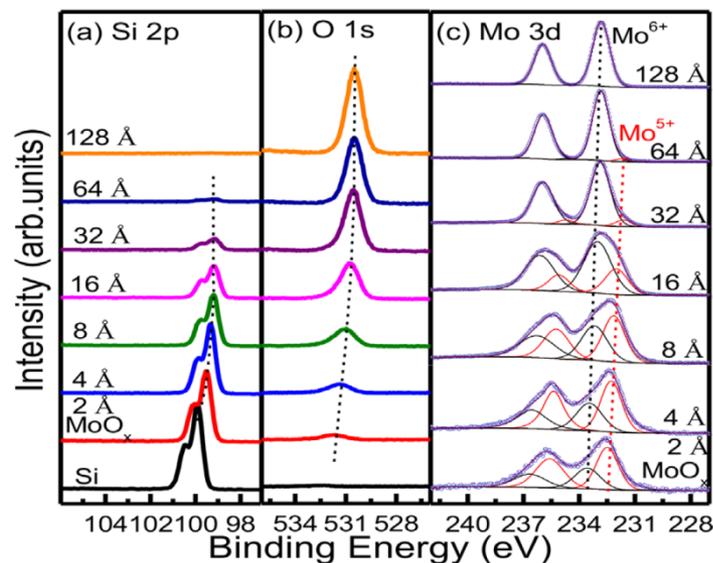
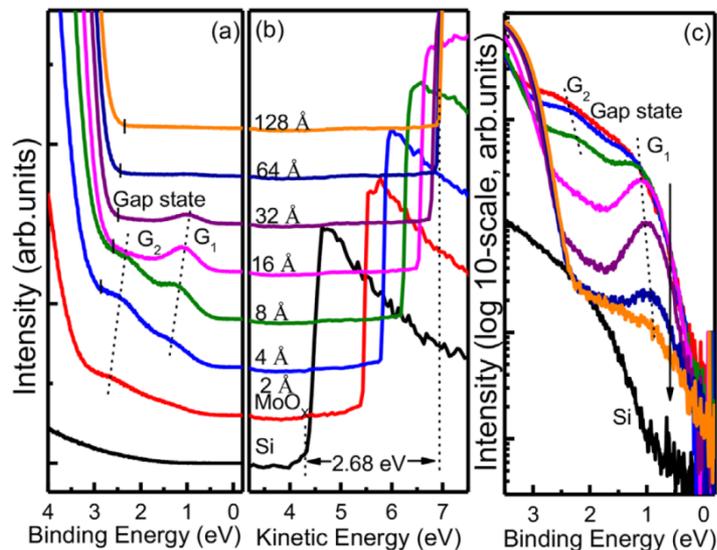
Impact of white light illumination (in UHV)



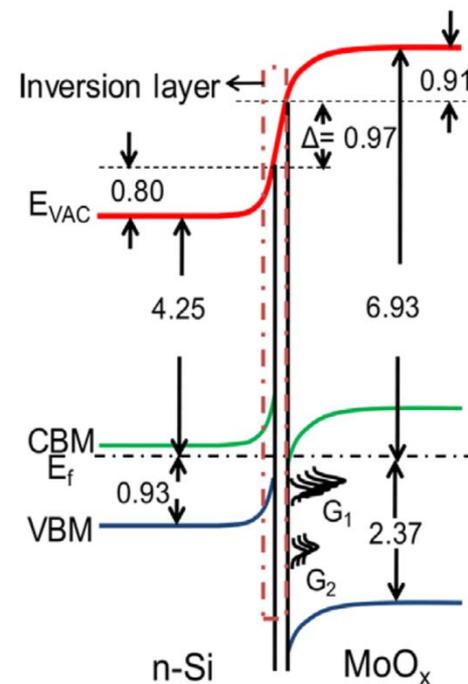
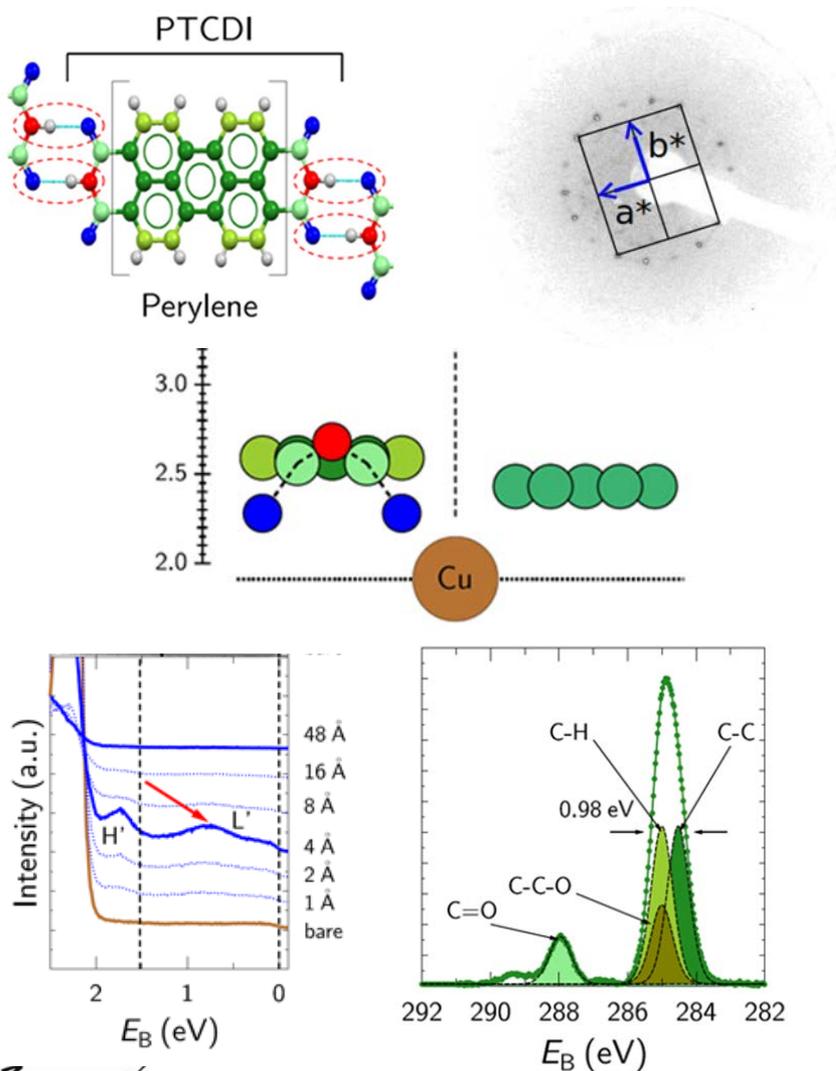
Traps mainly due to metallic lead (Pb^0), which are enriched at the surface.



Inversion layers in n-Si



Academic interfaces lead to understanding of device properties.



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Rongbin Wang

Lijia Liu

Baoquan Sun

Jiansheng Jie

Jianxin Tang

Jian Fan

Diamond

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